

tion, **9405**: audio output portion, **9406**: operation key, **9407**: external connection port, **9408**: antenna, **9501**: main body, **9502**: display portion, **9503**: housing, **9504**: external connection port, **9505**: remote control receiving portion, **9506**: image receiving portion, **9507**: battery, **9508**: audio input portion, **9509**: operation keys, **9510**: eyepiece portion

[0216] This application is based on Japanese Patent Application serial no. 2011-039621 filed with Japan Patent Office on Feb. 25, 2011, the entire contents of which are hereby incorporated by reference.

1. A light emitting device comprising:
 - a first electrode layer and a second electrode layer over a first substrate;
 - a structure body over the first electrode layer and the second electrode layer;
 - a first light-emitting layer over the first electrode layer and the structure body;
 - a second light-emitting layer over the second electrode layer and the structure body;
 - a third electrode layer over the first light-emitting layer;
 - a fourth electrode layer over the second light-emitting layer;
 - a bonding layer over the third electrode layer and the fourth electrode layer; and
 - a second substrate over the bonding layer,
 wherein the first light-emitting layer is separated from the second light-emitting layer by the structure body, and wherein at least a part of the structure body is in contact with the bonding layer.
2. The light-emitting device according to claim 1, wherein the third electrode layer is separated from the fourth electrode layer by the structure body.
3. The light-emitting device according to claim 1, wherein the first substrate and the second substrate have flexibility.
4. The light-emitting device according to claim 1, wherein each of the first electrode layer and the second electrode layer is electrically connected to a transistor.
5. The light-emitting device according to claim 1, wherein the second substrate has a colored layer which is capable of transmitting light of a specific wavelength band.
6. The light-emitting device according to claim 1, wherein each of the first light-emitting layer and the second light-emitting layer includes a hole injection layer, a hole transport layer, an electron transport layer, and an electron injection layer.
7. The light-emitting device according to claim 1, wherein each of the first light-emitting layer and the second light-emitting layer is capable of emitting white light.
8. The light-emitting device according to claim 1, wherein a side portion of the structure body protrudes from a bottom of the structure body in a direction parallel to the first substrate.
9. The light-emitting device according to claim 1, wherein the third electrode layer and the fourth electrode layer are electrically connected to a common electrode layer.
10. An electronic device using the light-emitting device described in claim 1.
11. A light emitting device comprising:
 - a first electrode layer and a second electrode layer over a first substrate;

- a structure body over the first electrode layer and the second electrode layer;
 - a first light-emitting layer over the first electrode layer and the structure body;
 - a second light-emitting layer over the second electrode layer and the structure body;
 - a third electrode layer over the first light-emitting layer;
 - a fourth electrode layer over the second light-emitting layer;
 - a bonding layer over the third electrode layer and the fourth electrode layer; and
 - a second substrate over the bonding layer,
- wherein the first light-emitting layer is separated from the second light-emitting layer by the structure body, and wherein at least a part of the structure body is in contact with the third electrode layer and the fourth electrode layer.
12. The light-emitting device according to claim 11, wherein the third electrode layer and the fourth electrode layer are continuous at the structure body.
 13. The light-emitting device according to claim 11, wherein the first substrate and the second substrate have flexibility.
 14. The light-emitting device according to claim 11, wherein each of the first electrode layer and the second electrode layer is electrically connected to a transistor.
 15. The light-emitting device according to claim 11, wherein the second substrate has a colored layer which is capable of transmitting light of a specific wavelength band.
 16. The light-emitting device according to claim 11, wherein each of the first light-emitting layer and the second light-emitting layer includes a hole injection layer, a hole transport layer, an electron transport layer, and an electron injection layer.
 17. The light-emitting device according to claim 11, wherein each of the first light-emitting layer and the second light-emitting layer is capable of emitting white light.
 18. The light-emitting device according to claim 11, wherein a side portion of the structure body protrudes from a bottom of the structure body in a direction parallel to the first substrate.
 19. The light-emitting device according to claim 11, wherein the third electrode layer and the fourth electrode layer are electrically connected to a common electrode layer.
 20. An electronic device using the light-emitting device described in claim 11.
 21. A light emitting device comprising:
 - a first electrode layer and a second electrode layer over a first substrate;
 - a partition wall over the first electrode layer and the second electrode layer;
 - a structure body over the partition wall;
 - a first light-emitting layer over the first electrode layer, the partition wall and the structure body;
 - a second light-emitting layer over the second electrode layer, the partition wall and the structure body;
 - a third electrode layer over the first light-emitting layer;
 - a fourth electrode layer over the second light-emitting layer;
 - a bonding layer over the third electrode layer and the fourth electrode layer; and
 - a second substrate over the bonding layer,